

Supplementary Information

# Comparative Study of Field-Effect Transistors Based on Graphene Oxide and CVD Graphene in Highly Sensitive NT-proBNP Aptasensors

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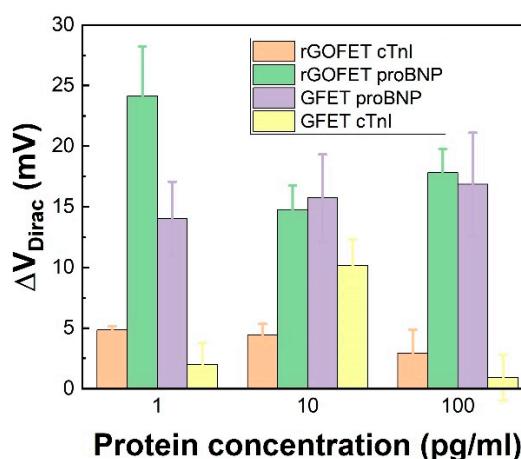
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**Figure S1.** Sensitivity of rGO-FET and GFET based biosensors to nonspecific biomarkers (cTnI and proBNP).